## MMBD4148 / SE / CC / CA

Silicon Epitaxial Planar Switching Diode

| 4148 | 4148 SE | 4148 CC | 4148 CA |
| :--- | :--- | :--- | :--- |

Absolute Maximum Ratings ( $\mathrm{T}_{\mathrm{a}}=25^{\circ} \mathrm{C}$ )

| Parameter | Symbol | Value | Unit |
| :--- | :---: | :---: | :---: |
| Maximum Repetitive Reverse Voltage | $\mathrm{V}_{\text {RRM }}$ | 100 | V |
| Reverse Voltage | $\mathrm{V}_{R}$ | 75 | V |
| Average Rectified Forward Current | $\mathrm{I}_{\mathrm{F}(\mathrm{AV})}$ | 200 | mA |
| DC Forward Current | $\mathrm{I}_{\text {FM }}$ | 600 | mA |
| Recurrent Peak Forward Current | $\mathrm{I}_{\text {FRM }}$ | 700 | mA |
| Non-repetitive Peak Forward Surge Current at $=1 \mathrm{~s}$ | $\mathrm{I}_{\text {FSM }}$ | 1 | A |
| Total Device Dissipation | $\mathrm{P}_{\text {tot }}$ | 350 | mW |
| Operating Junction Temperature | $\mu \mathrm{s}$ | $\mathrm{T}_{\mathrm{j}}$ | 150 |
| Storage Temperature Range | $\mathrm{T}_{\text {stg }}$ | -55 to +150 | ${ }^{\circ} \mathrm{C}$ |

Characteristics at $\mathrm{T}_{\mathrm{a}}=25^{\circ} \mathrm{C}$

| Parameter | Symbol | Min. | Max. | Unit |
| :---: | :---: | :---: | :---: | :---: |
| Forward Voltage at $I_{F}=10 \mathrm{~mA}$ | $V_{F}$ | - | 1 | V |
| Reverse Breakdown Voltage at $I_{R}=100 \mu \mathrm{~A}$ <br> at $\mathrm{I}_{\mathrm{R}}=5 \mu \mathrm{~A}$ | $\mathrm{V}_{(\mathrm{BR}) \mathrm{R}}$ | $\begin{gathered} 100 \\ 75 \end{gathered}$ | - | V |
| $\begin{aligned} & \text { Reverse Current } \\ & \text { at } \mathrm{V}_{\mathrm{R}}=20 \mathrm{~V} \\ & \text { at } \mathrm{V}_{\mathrm{R}}=75 \mathrm{~V} \\ & \text { at } \mathrm{V}_{\mathrm{R}}=20 \mathrm{~V}, \mathrm{~T}_{\mathrm{a}}=150^{\circ} \mathrm{C} \end{aligned}$ | $I_{\text {R }}$ | - | $\begin{gathered} 25 \\ 5 \\ 50 \end{gathered}$ | nA <br> $\mu \mathrm{A}$ <br> $\mu \mathrm{A}$ |
| Reverse Recovery Time at $\mathrm{I}_{\mathrm{F}}=10 \mathrm{~mA}, \mathrm{~V}_{\mathrm{R}}=6 \mathrm{~V}, \mathrm{I}_{\mathrm{RR}}=1 \mathrm{~mA}, \mathrm{R}_{\mathrm{L}}=100 \Omega$ | $\mathrm{t}_{\mathrm{rr}}$ | - | 4 | ns |
| Total Capacitance at $\mathrm{V}_{\mathrm{R}}=0 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}$ | $\mathrm{C}_{\text {T }}$ | - | 4 | pF |





Fig. 2 Forward Characteristics


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